

Ultrafast Recovery Rectifier

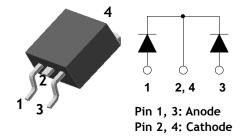
Ultrafast Recovery Power Rectifier

Features and Benefits

- Low forward drop voltage
- Dual common cathode rectifier construction
- · Ultrafast recovery time and high speed switching
- Full lead (Pb)-free device and RoHS compliant device

Applications

- Switching power supply
- Power inverters
- Power conversion system



D2-PAK

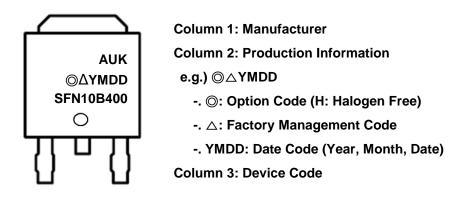
General Description

The SFN10B400D2 is ideally as boost diode in discontinuous or critical mode power factor corrections. The planar structure and the platinum doper life time control guarantee the best overall performance, ruggedness reliability characteristics. The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

Ordering Information

Part Number	Marking Code	Package	Packaging
SFN10B400D2	SFN10B400	D2-PAK	Tape & Reel

Marking Information



Absolute Maximum Ratings (Limiting values at 25°C, unless otherwise specified)

Characteristic		Symbol	Ratings	Unit	
Maximum repetitive reverse voltage Maximum working peak reverse voltage Maximum DC blocking voltage		V _{RRM} V _{RWM} V _R	400	V	
Maximum average forward restified ourrept	Per diode	I _{F(AV)}	5		
Maximum average forward rectified current	Total device		10	A	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load per diode		I _{FSM}	100	А	
Storage temperature range		T _{stg}	-45 to +150	°C	
Maximum operating junction temperature		TJ	150	C	

Thermal Characteristics (Per diode)

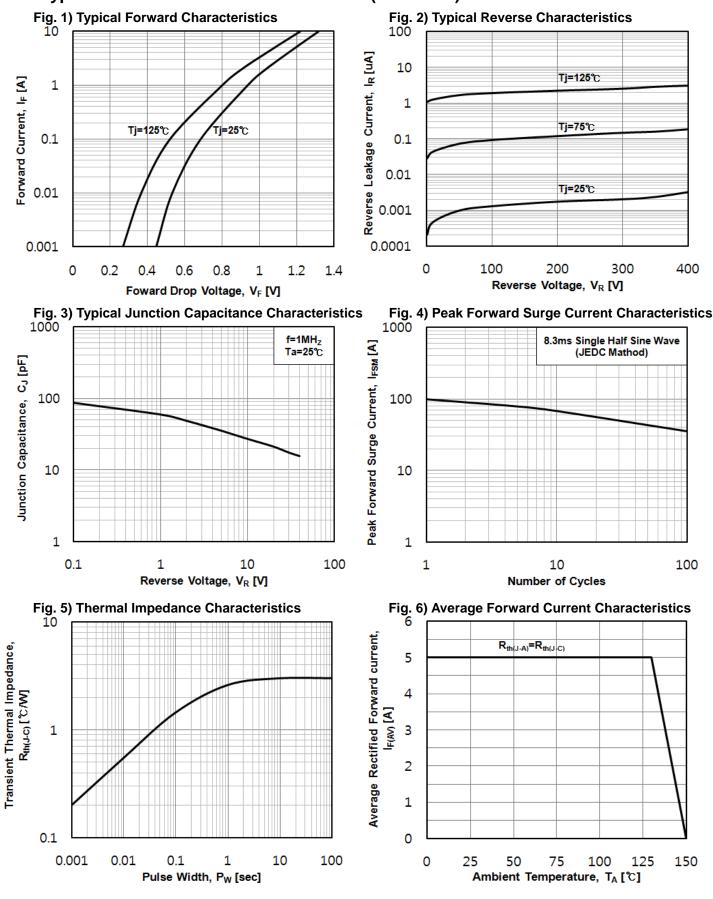
Characteristic		Symbol	Ratings	Unit	
Maximum thermal resistance junction to case	Per diode	R _{th(J-C)}	3.0	°C 44	
	Total device		2.6	°C/W	

Electrical Characteristics (Per diode)

Characteristic	Symbol	Test Condition		Min.	Тур.	Max.	Unit
Peak forward voltage drop	V _{FM} ¹⁾	I _{FM} = 5A	T _J =25℃	-	1.20	1.60	V
Reverse leakage current	I _{RM} ²⁾	$V_{R} = V_{RRM}$	TJ=25℃	-	-	5	uA
			T _J =125℃	-	-	200	
Reverse recovery time	t _{rr}	I _F = 1A, di/dt = -100 A/us		-	18	22	ns
Junction capacitance	C _j	$V_R = 10V_{DC}$, f=1MHz		-	27	-	pF

 $^{1)}$ Pulse test: $t_{P}{\leq}380us,$ Duty cycle ${\leq}2\%$

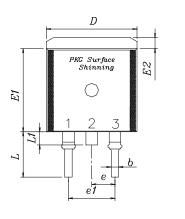
 $^{2)}$ Pulse test: t_p≤20ms, Duty cycle≤2%

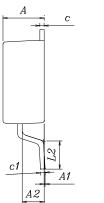


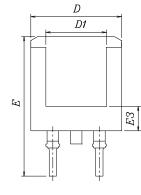
Typical Electrical Characteristic Curves (Per diode)

Rev. date: 27-OCT-15

Package Outline Dimensions (Unit: mm)

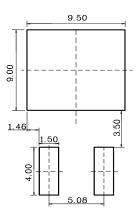






SYMBOL		NOTE		
SIMDUL	MINIMUM	NUTE		
А	4.35	4.50	4.65	
A1	—	_	0.15	
A2	2.20	2.40	2.60	
b	0.70	0.80	0.90	
С	0.40	0.50	0.60	
с1	0.40	0.50	0.60	
D	9.80	10.00	10.20	
D1	6.40	6.60	6.80	
E	15.00	15.40	15.80	
E1	9.05	9.20	9.35	
E2	1.00	1.20	1.40	
E3	2.50	2.70	2.90	
е	2.34	2.54	2.74	
e1	4.88	5.08	5.28	
L	4.60	5.00	5.40	
L1	1.40	1.45	1.50	
L2	2.50	_	_	

Recommend PCB solder land (Unit: mm)



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